Analog Power AM3455P

## P-Channel 30V (D-S) MOSFET

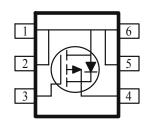
These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r <sub>DS(on)</sub> Provides Higher Efficiency and
	Extends Battery Life

- Low Gate Charge
- Fast Switch
- Miniature TSOP-6 Surface Mount Package Saves Board Space

PRODUCT SUMMARY			
$\left  V_{\mathrm{DS}} \left( \mathrm{V} \right) \right  = r_{\mathrm{DS}(\mathrm{on})} \left( \Omega \right) = \left  I_{\mathrm{D}} \left( \mathrm{A} \right) \right $			
-30	0.112	3.4	
-30	$0.172 @ V_{GS} = 4.5V$	2.7	





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			-30	V	
Gate-Source Voltage			±20	V	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	T.,	3.4		
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	П	2.6	A	
Pulsed Drain Current <sup>b</sup>			±20		
Continuous Source Current (Diode Conduction) <sup>a</sup>			1.7	Α	
D D: : ,: a	$T_A=25^{\circ}C$	$\Big]_{\mathbf{D}_{-}}$	2.0	$_{ m W}$	
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	Гр	1.3	VV	
Operating Junction and Storage Temperature Range		$T_{J}, T_{stg}$	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
M · I · · a	t <= 5 sec	R <sub>THJA</sub>	62.5	°C/W		
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State		110			

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)							
D	C1	T C	Limits			TT	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1.0			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			1	4	
Zero Gate Voltage Diam Current	IDSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			50	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			A	
D i G O D i A		$V_{GS} = 10 \text{ V}, I_D = 3.4 \text{ A}$			112	mΩ	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 2.7 \text{ A}$			172		
Forward Tranconductance <sup>A</sup>	gs	$V_{DS} = 4.5 \text{ V}, I_D = 3.4 \text{ A}$		6		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_S = 0.75 \text{ A}, V_{GS} = 0 \text{ V}$			1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			4.5			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 30 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 3.4 \text{ A}$		1.4		nC	
Gate-Drain Charge	$Q_{gd}$			2.4		1	
Turn-On Delay Time	td(on)			9			
Rise Time	$t_{\rm r}$	$V_{DD} = 30 \text{ V},  R_L = 30 \Omega,  I_D = 1 \text{ A},$		12		,,,	
Turn-Off Delay Time	td(off)	$V_{GEN} = 10 \text{ V}$		25		ns	
Fall-Time	tf			14			

## Notes

- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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